



Parameter	Rating	Units
Drain-to-Source Voltage - V_{DS}	350	V
Max On-Resistance - $R_{DS(on)}$	14	Ω
Max Power	2.5	W

Features

- 350V Drain-to-Source Voltage
- Depletion Mode Device Offers Low $R_{DS(on)}$ at Cold Temperatures
- Low On-resistance: 8Ω (Typical) @ 25°C
- Low $V_{GS(off)}$ Voltage: -2.0V to -3.6V
- High Input Impedance
- Low Input and Output Leakage
- Small Package Size SOT-223
- PC Card (PCMCIA) Compatible
- PCB Space and Cost Savings

Applications

- Support Component for LITELINK™ Data Access Arrangement (DAA)
- Telecommunications
- Normally On Switches
- Ignition Modules
- Converters
- Security
- Power Supplies

Description

The CPC5602 is an N-channel depletion mode Field Effect Transistor (FET) that utilizes IXYS Integrated Circuits Division's proprietary third generation vertical DMOS process. The third generation process realizes world class, high voltage MOSFET performance in an economical silicon gate process. The vertical DMOS process yields a highly reliable device, particularly in difficult application environments such as telecommunications, security, and power supplies.

One of the primary applications for the CPC5602 is as a linear regulator/hook switch for the LITELINK family of Data Access Arrangements (DAA) Devices CPC5620A, CPC5621A, and CPC5622A.

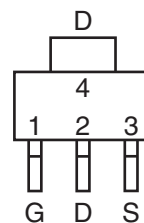
The CPC5602 has a typical on-resistance of 8Ω , a drain-to-source voltage of 350V, and is available in an SOT-223 package. As with all MOS devices, the FET structure prevents thermal runaway and thermal-induced secondary breakdown.

Ordering Information

Part #	Description
CPC5602C	N-Channel Depletion Mode FET, SOT-223 Pkg. Cut-Tape, Available in Quantities of 200, 400, 600, and 800 Only (see Note 1)
CPC5602CTR	N-Channel Depletion Mode FET, SOT-223 Pkg. Tape and Reel (1000/Reel)

Note 1: Orders for 1000 or greater must be for the "CTR" part option and in increments of 1000.

Package Pinout



Pin Number	Name
1	GATE
2	DRAIN
3	SOURCE
4	DRAIN

Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Drain-to-Source Voltage (V_{DS})	350	V
Gate-to-Source Voltage (V_{GS})	±20	V
Total Package Dissipation	2.5	W
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

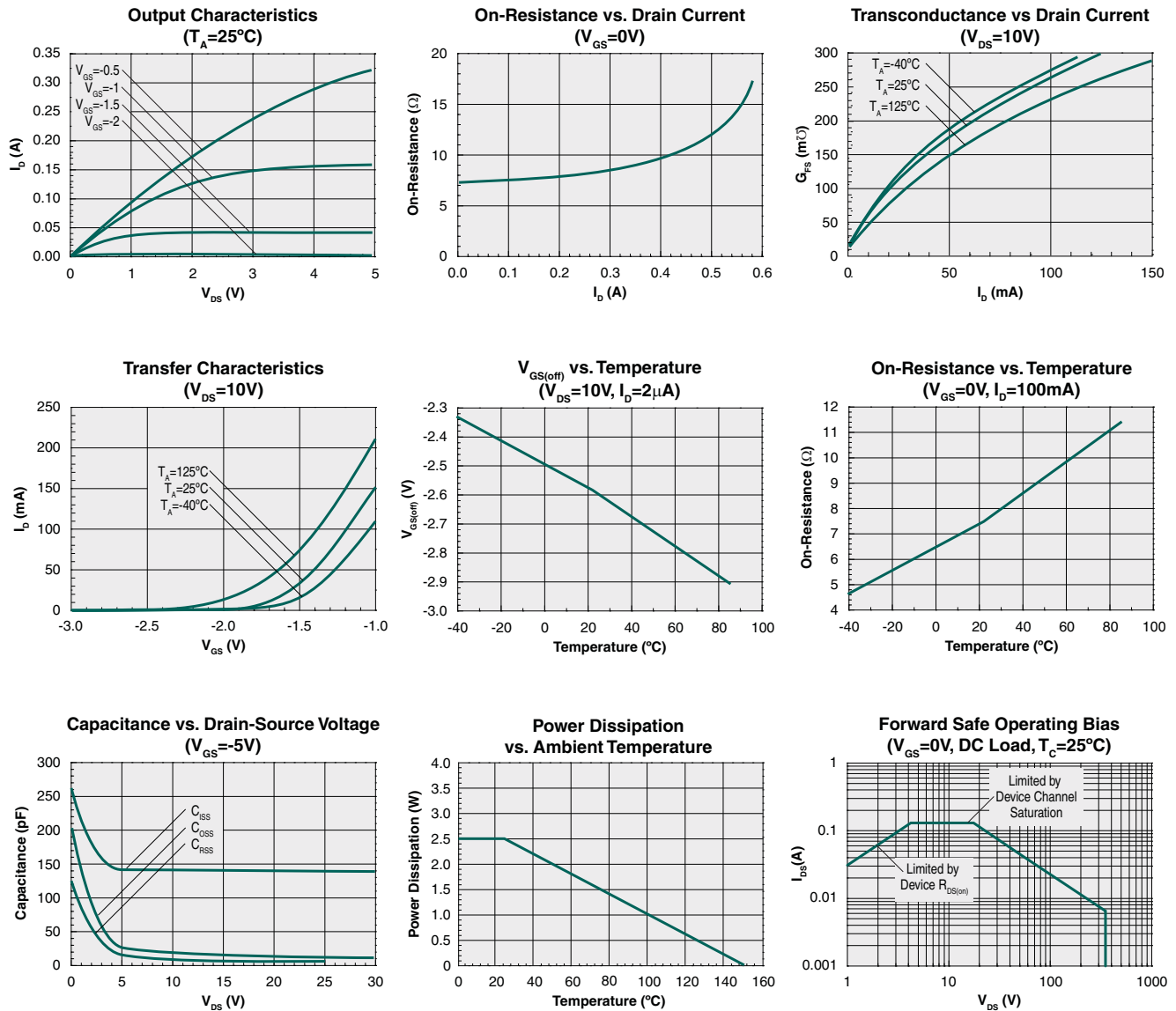
Electrical Characteristics @25°C (Unless Otherwise Specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Gate-to-Source Off Voltage	$V_{GS(off)}$	$I_D = 2\mu A, V_{DS}=10V, V_{DS}=100V$	-3.6	-2.62	-2	V
Drain-to-Source Leakage Current	$I_{DS(off)}$	$V_{GS} = -5V, V_{DS}=190V$	-	-	20	nA
		$V_{GS} = -5V, V_{DS}=350V$	-	-	1	μA
Drain Current	I_D	$V_{GS} = -2.7V, V_{DS}=5V, V_{DS}=50V$	-	-	5	mA
		$V_{GS} = -0.57V, V_{DS}=5V$	130	-	-	mA
On-Resistance	$R_{DS(on)}$	$V_{GS} = -0.35V, I_{DS}=50mA$	-	8	14	Ω
Gate Leakage Current	I_{GSS}	$V_{GS}=10V, V_{GS}=-10V$	-	-	0.1	μA
Gate Capacitance	C_{ISS}	$V_{DS}=V_{GS}=0V$	-	-	300	pF

Thermal Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Thermal Resistance	$R_{\theta JC}$	-	-	-	14	°C/W

PERFORMANCE DATA*



*The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
CPC5602C	MSL 1

ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
CPC5602C	260°C for 30 seconds

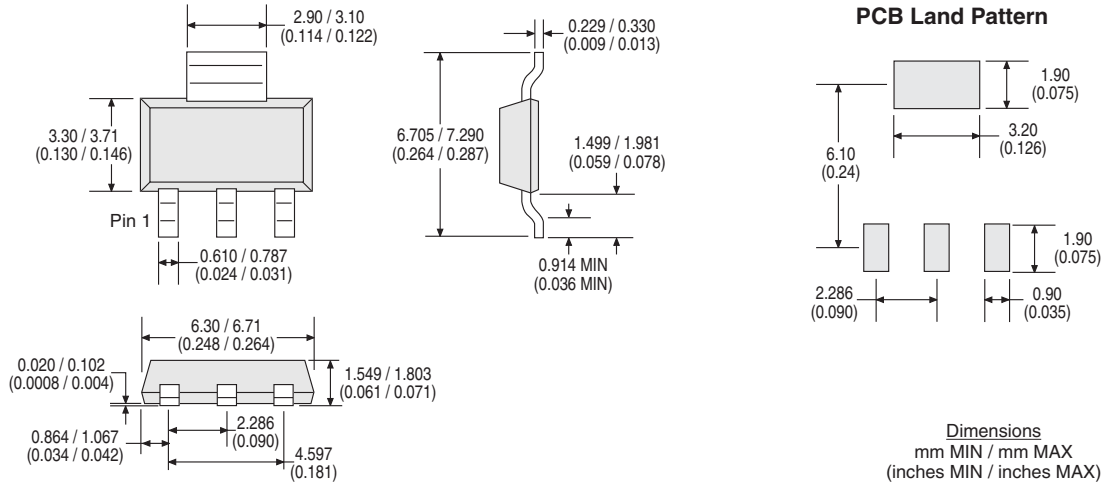
Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable, and the use of a short drying bake may be necessary. Chlorine-based or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.

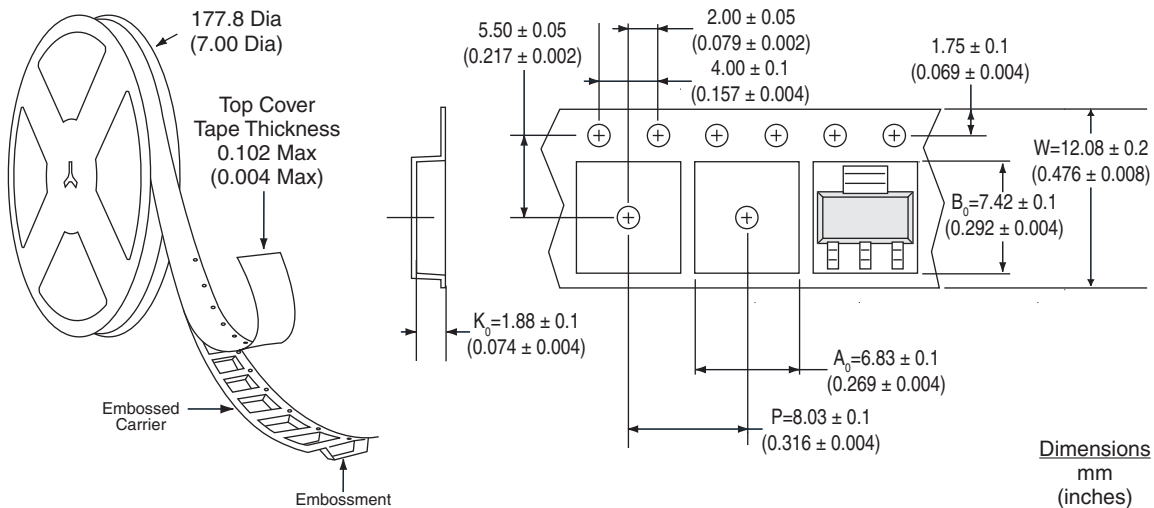


MECHANICAL DIMENSIONS

CPC5602C



CPC5602CTR Tape & Reel



For additional information please visit our website at: www.ixysic.com

IXYS Integrated Circuits Division makes no representations or warranties with respect to the accuracy or completeness of the contents of this publication and reserves the right to make changes to specifications and product descriptions at any time without notice. Neither circuit patent licenses nor indemnity are expressed or implied. Except as set forth in IXYS Integrated Circuits Division's Standard Terms and Conditions of Sale, IXYS Integrated Circuits Division assumes no liability whatsoever, and disclaims any express or implied warranty, relating to its products including, but not limited to, the implied warranty of merchantability, fitness for a particular purpose, or infringement of any intellectual property right.

The products described in this document are not designed, intended, authorized or warranted for use as components in systems intended for surgical implant into the body, or in other applications intended to support or sustain life, or where malfunction of IXYS Integrated Circuits Division's product may result in direct physical harm, injury, or death to a person or severe property or environmental damage. IXYS Integrated Circuits Division reserves the right to discontinue or make changes to its products at any time without notice.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9